

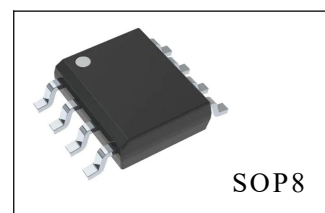
### General Description

The D8522 (dual) is low cost, rail-to-rail input and output voltage feedback amplifier. It has a wide input common mode voltage range and output voltage swing, and take the minimum operating supply voltage down to 2.1V. The maximum recommended supply voltage is 5.5V. All are specified over the extended -40°C to +125°C temperature range.

The D8522 provides 150kHz bandwidth at a low current consumption of 5.5μA per amplifier. Very low input bias currents enable the D8522 to be used for integrators, photodiode amplifiers, and piezoelectric sensors. Rail-to-rail input and output are useful to designers for buffering ASIC in single-supply systems.

Application for this amplifier includes safety monitoring, portable equipment, battery and power supply control, and signal conditioning and interfacing for transducers in very low power systems.

The D8522 dual comes in SOP8 package.



### Features

- Low Cost
- Rail-to-Rail Input and Output:  
1mV Typical VOS
- Unity Gain Stable
- Gain-Bandwidth Product: 150kHz
- Supply Voltage Range: 2.1V to 5.5V
- Input Voltage Range:  
-0.1V to +5.6V with  $V_S = 5.5V$
- Low Supply Current: 5.5μA/Amplifier
- Small Packaging

### Applications

- ASIC Input or Output Amplifier
- Sensor Interface
- Piezoelectric Transducer Amplifier
- Medical Instrumentation
- Mobile Communication
- Audio Output      Portable Systems
- Smoke Detectors
- Mobile Telephone
- Notebook PC
- PCMCIA Cards
- Battery-Powered Equipment

### Package Information

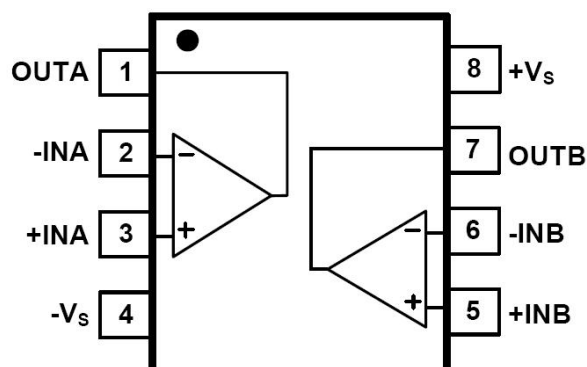
Part NO.	Package Description	Package Marking	Package Option
D8522F	SOP8	CHMC D8522F SXXXX	100/Tube 4000/Reel

CHMC:Trademark

D8522F:Part NO.

SXXXX:Lot NO.

## Pin Configuration



**D8522(SOP8)**

## Absolute Maximum Ratings

Characteristic		Limit	Unit
Supply voltage		6	V
Common mode input voltage		$(-V_s)-0.3 \sim (+V_s)+0.3$	V
Storage temperature range		-65 ~ +150	°C
Junction temperature range		150	°C
Operating temperature range		-40 ~ +125	°C
Package thermal resistance@Ta=25 °C		125	°C /W
Lead temperature (Soldering 10sec)		260	°C
ESD susceptibility	HBM	4000	V
	MM	400	

\*Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## Electrical Characteristics

( $T_A=25^{\circ}\text{C}$ ,  $V_S=+5\text{V}$ ,  $R_L=500\text{k}\Omega$  connected to  $V_S/2$  and  $V_{OUT}=V_S/2$ , unless otherwise specified.)

Characteristic	Symbol	Conditions	Min	Typ	Max	Unit
Input offset voltage	$V_{OS}$			1	3.5	mV
Quiescent current/amplifier	$I_Q$			5.5		$\mu\text{A}$
Open-Loop voltage gain	$G_V$	$V_O=0.015\text{V}$ to $4.985\text{V}$ , $R_L=500\text{k}\Omega$	90	110		dB
		$V_O=0.1\text{V}$ to $4.9\text{V}$ , $R_L=100\text{k}\Omega$	88	108		
Common mode rejection ratio	CMRR	$V_S=5.5\text{V}$ , $-0.1\text{V} < V_{CM} < 5.6\text{V}$	60	87		dB
		$V_S=5.5\text{V}$ , $-0.1\text{V} < V_{CM} < 4\text{V}$	70	114		
Power supply rejection ratio	PSRR	$V_S=2.5\text{V}$ , $-0.1\text{V} < V_{CM} < 5.6\text{V}$	65	94		dB
Output current	$I_{SOURCE}$	$R_L=10\Omega$ to $V_S/2$	61	87		mA
	$I_{SINK}$		60	76		
Output voltage swing	$V_{OH}$		4.990	4.997		V
	$V_{OL}$			0.005	0.01	
Gain-Bandwidth product	GBP			150		kHz
Slew rate	SR	$R_L=100\text{k}\Omega$		0.05		$\text{V}/\mu\text{s}$
Voltage noise density	$e_n$	$f=1\text{kHz}$		85		$\text{nV}/\sqrt{\text{Hz}}$
		$f=10\text{kHz}$		44		

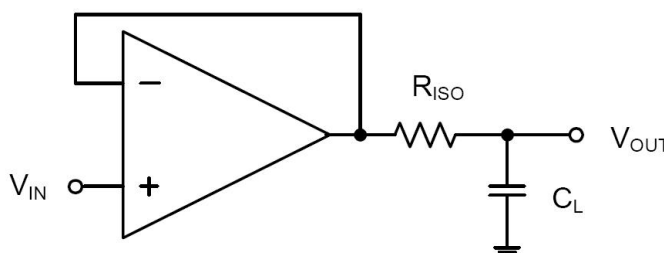
## Application Summary

### Driving Capacitive Loads

The D8522 can directly drive 250pF in unity-gain without oscillation. The unity-gain follower (buffer) is the most sensitive configuration to capacitive loading. Direct capacitive loading reduces the phase margin of amplifiers

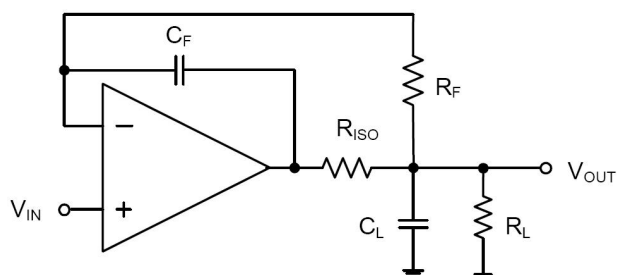
and this results in ringing or even

oscillation. Applications that require greater capacitive driving capability should use an isolation resistor between the output and the capacitive load like the circuit in Fig1. The isolation resistor  $R_{ISO}$  and the load capacitor  $C_L$  form a zero to increase stability. The bigger the  $R_{ISO}$  resistor value, the more stable  $V_{OUT}$  will be. Note that this method results in a loss of gain accuracy because  $R_{ISO}$  forms a voltage divider with the  $R_{LOAD}$ .



**Fig1. Indirectly Driving Heavy Capacitive Load**

An improved circuit is shown in Fig2. It provides DC accuracy as well as AC stability.  $R_F$  provides the DC accuracy by connecting the inverting signal with the output.  $C_F$  and  $R_{ISO}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop.

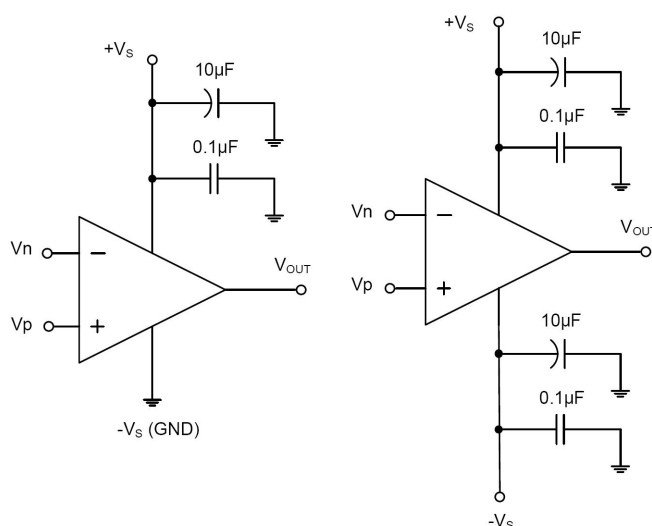


**Fig2. Indirectly Driving Heavy Capacitive Load with DC Accuracy**

For non-buffer configuration, there are two other ways to increase the phase margin: (a) by increasing the amplifier's gain or (b) by placing a capacitor in parallel with the feedback resistor to counteract the parasitic capacitance associated with inverting node.

## Power-Supply Bypassing and Layout

The D8522 operates from either a single +2.1V to +5.5V supply or dual  $\pm 1.05V$  to  $\pm 2.75V$  supplies. For single-supply operation, bypass the power supply + $V_S$  with a 0.1 $\mu F$  ceramic capacitor which should be placed close to the + $V_S$  pin. For dual-supply operation, both the + $V_S$  and the - $V_S$  supplies should be bypassed to ground with separate 0.1 $\mu F$  ceramic capacitors. 2.2 $\mu F$  tantalum capacitor can be added for better performance.

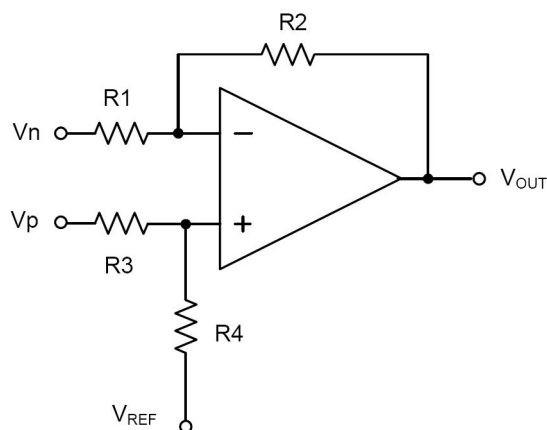


**Fig3. Amplifier with Bypass Capacitors**

### Differential Amplifier

The circuit shown in Fig4 performs the difference function. If the resistor ratios are equal to ( $R4/R3 = R2/R1$ ), then

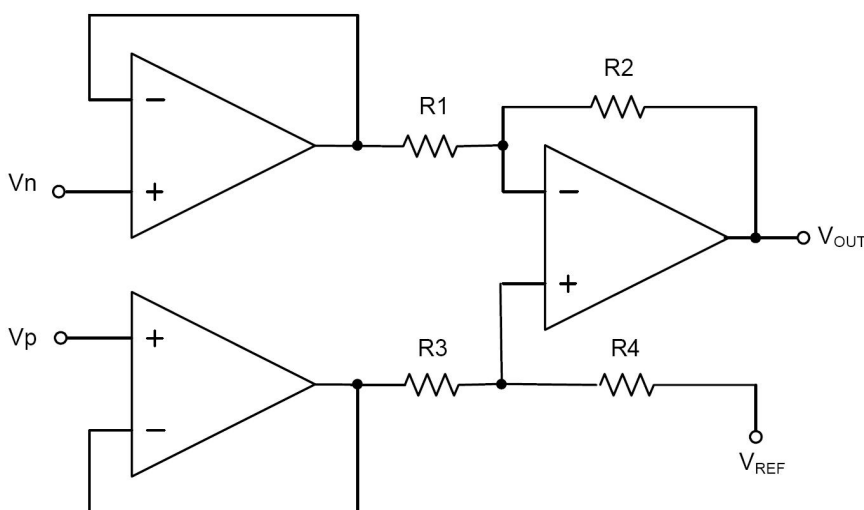
$$V_{OUT} = (V_p - V_n) \times R2/R1 + V_{REF}.$$



**Fig4. Differential Amplifier**

### Instrumentation Amplifier

The circuit in Fig5 performs the same function as that in Fig4 but with a high input impedance.

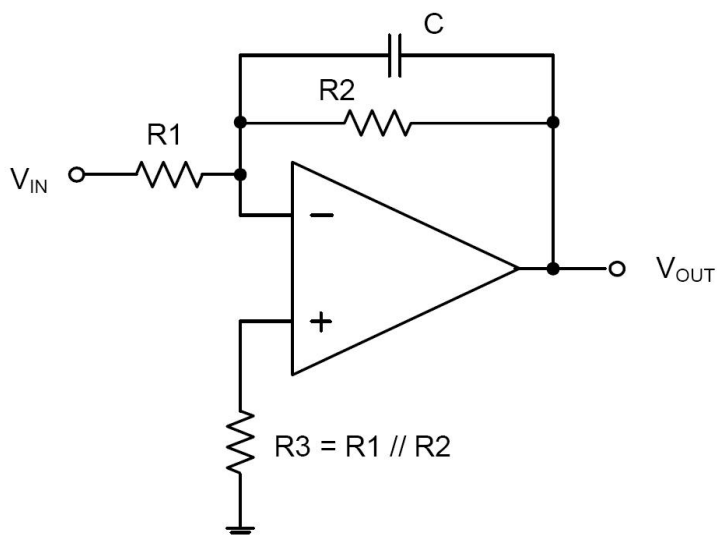


**Fig5. Instrumentation Amplifier**

### Low Pass Active Filter

The low pass filter shown in Fig6 has a DC gain of  $(-R2/R1)$  and the -3dB corner frequency is  $1/2 \pi R2C$ . Make sure the filter bandwidth is within the bandwidth of the amplifier. The large values of feedback resistors can couple with parasitic capacitance and cause undesired

effects such as ringing or oscillation in high-speed amplifiers. Keep resistor values as low as possible and consistent with output loading consideration.

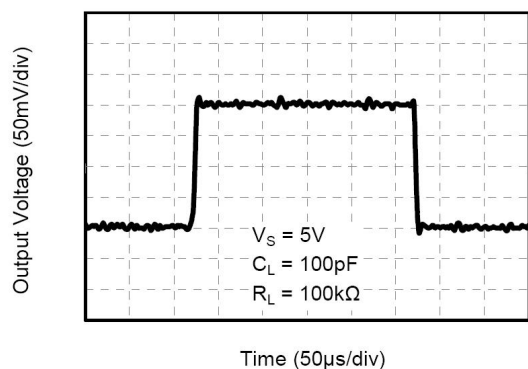


**Fig6. Low Pass Active Filter**

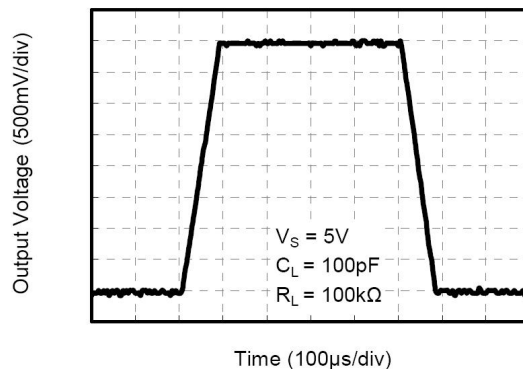
## Characteristics curves

At  $T_A = +25^\circ\text{C}$ ,  $V_S = +5\text{V}$  and  $R_L = 500\text{k}\Omega$  connected to  $V_S/2$ , unless otherwise noted.

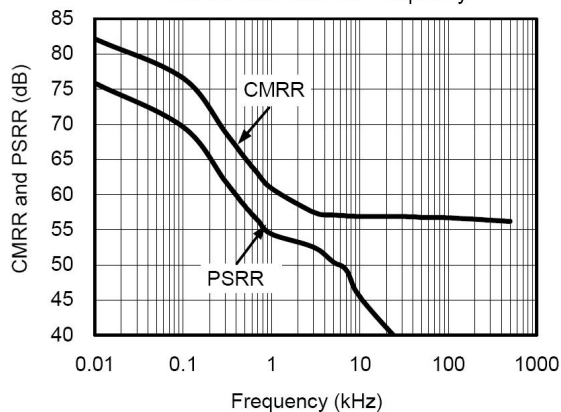
Small Signal Step Response



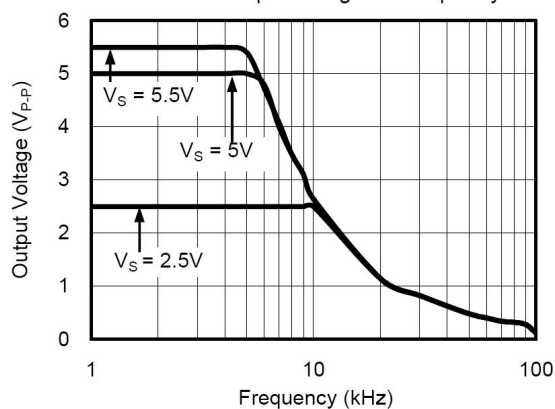
Large Signal Step Response



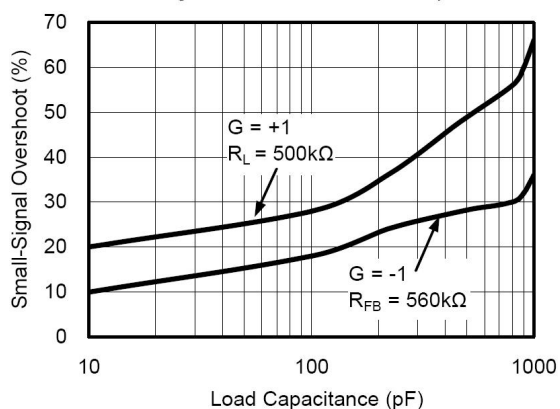
CMRR and PSRR vs. Frequency



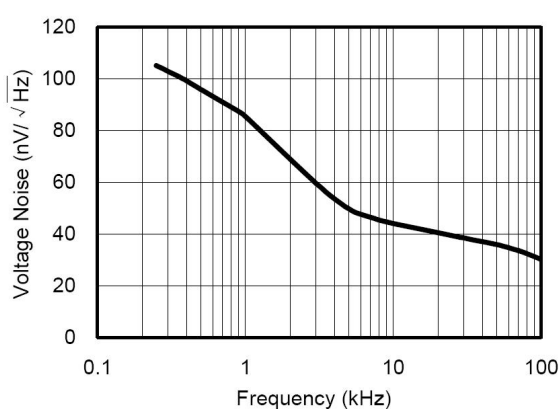
Maximum Output Voltage vs. Frequency

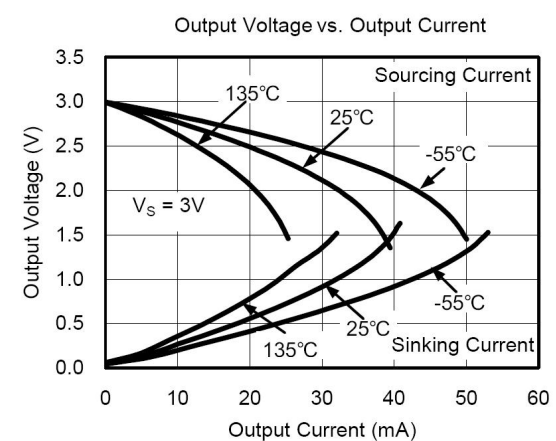
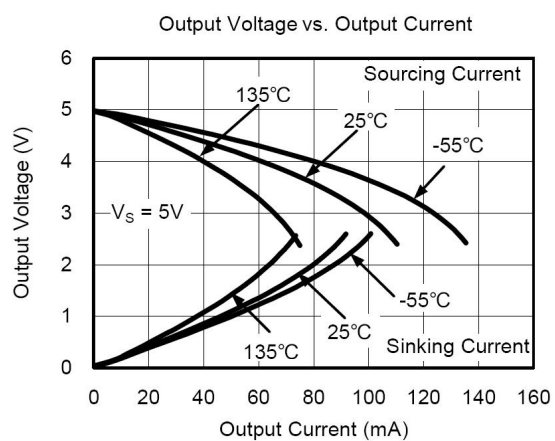
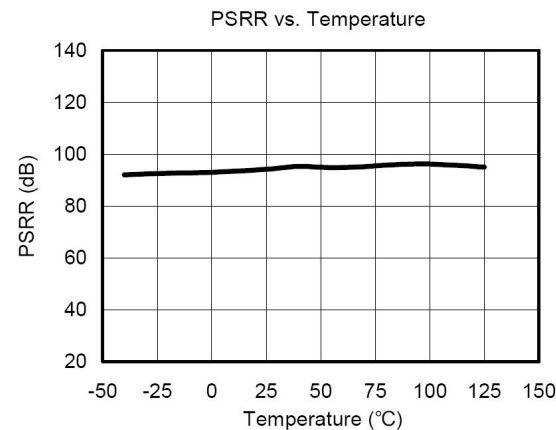
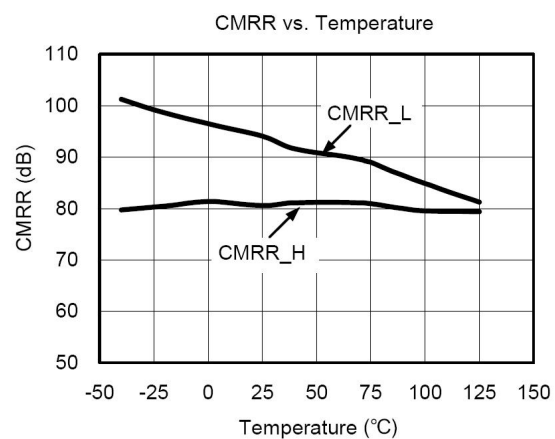
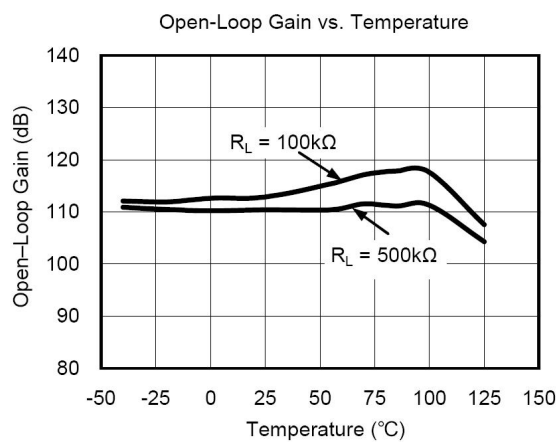
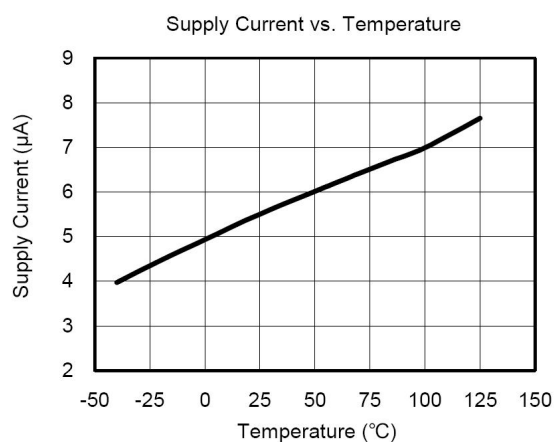


Small-Signal Overshoot vs. Load Capacitance

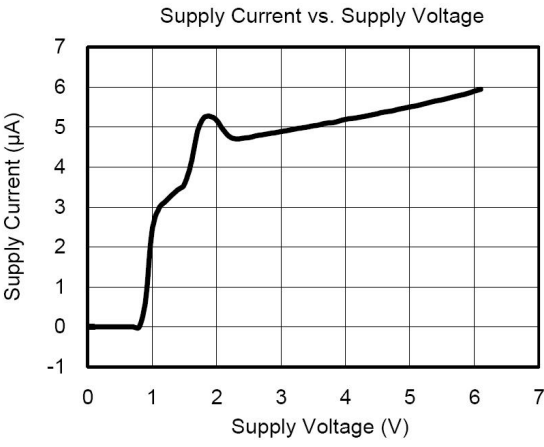
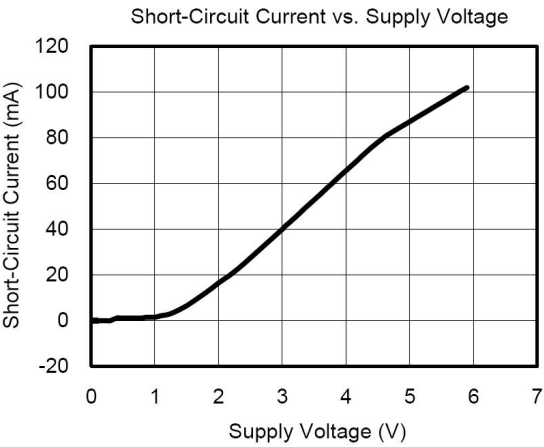


Input Voltage Noise Spectral Density vs. Frequency





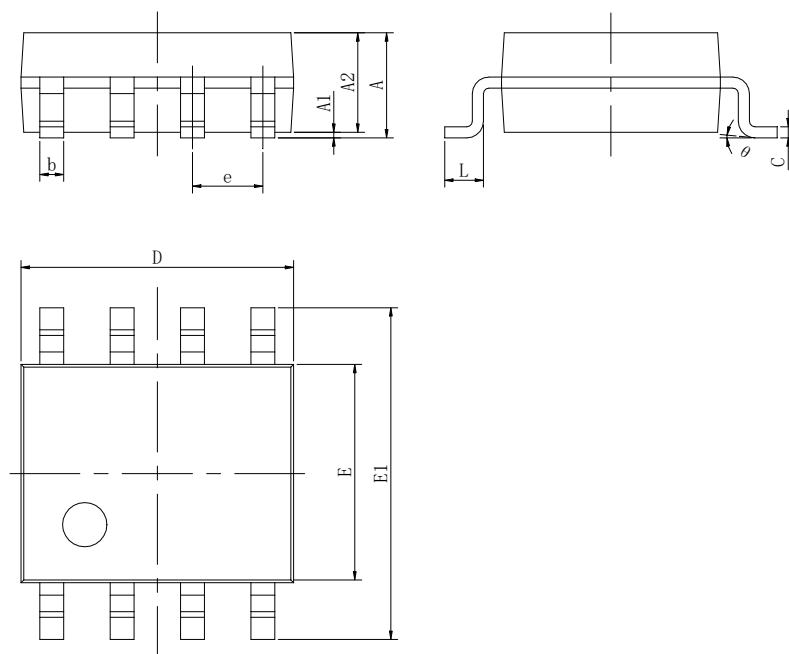




## Outline Dimensions

SOP8

Unit: mm



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.800	0.053	0.071
A1	0.000	0.250	0.000	0.010
A2	1.250	1.550	0.053	0.061
b	0.300	0.510	0.011	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.201
E	3.800	4.000	0.150	0.157
E1	5.800	6.300	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

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